## INTEGRATED CIRCUITS



Product specification Supersedes data of 1999 Apr 05

2000 Jun 19





## 20-bit bus switch with precharged outputs and Schottky undershoot protection for live insertion

## **CBT6820**

- TTL compatible inputs and outputs
- 5 Ω switch connection between two port A and port B
- Thin shrink small outline (TSSOP)
- Undershoot protection included to prevent shoot through level changes
- Bias voltage pre-charges the outputs to minimize signal distortion during live insertion
- Latch-up protection exceeds 500 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114, 200 V MM per JESD22-A115 and 1000 V CDM per JESD22-C101

#### DESCRIPTION

The CBT6820 provides twenty bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows bi-directional connections to be made while adding near-zero propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The device is organized as two 10-bit switch with individual enable (OE) input. When OE is low, the switch is on and port A is connected to port B. When OE is high, the switch between port A and port B is open and the B port is precharged to BIASV through the equivalent of a 10 k $\Omega$  resistor.

Special clamp circuitry and Schottky diode clamps to ground are used to prevent an under voltage on the A side (Vin < GND) from causing the B side precharge voltage to drop below the "1" state.

#### **PIN CONFIGURATION**

BIASV 1	48	1 <del>0E</del>
1A1 2	47	2 <del>0E</del>
1A2 3	46	1B1
1A3 4	45	1B2
1A4 5	44	1B3
1A5 6	43	1B4
1A6 7	42	1B5
GND 8	41	GND
1A7 9	40	1B6
1A8 10	39	1B7
1A9 11	38	1B8
1A10 12	37	1B9
2A1 13	36	1B10
2A2 14	35	2B1
V <sub>CC</sub> 15	34	2B2
2A3 16	33	2B3
GND 17	32	GND
2A4 18	31	2B4
2A5 19	30	2B5
2A6 20	29	2B6
2A7 21	28	2B7
2A8 22	27	2B8
2A9 23	26	2B9
2A10 24	25	2B10
		SA00520

#### QUICK REFERENCE DATA

SYMBC	DL	PARAMETER CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V		TYPICAL	UNIT
t <sub>PLH</sub> /t <sub>PF</sub>		Propagation delay An to Bn or Bn to An	$C_L = 50 \text{ pF}, V_{CC} = 5 \text{ V}$	0.25	ns
C <sub>IN</sub>		Input capacitance		4.5	pF
C <sub>I/O</sub>		Input/output capacitance	Outputs disabled; $V_0 = 0 V \text{ or } V_{CC}$	9.5	pF

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
48-Pin Plastic TSSOP Type II	–40°C to +85°C	CBT6820 DGG	SOT362-1

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#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	BIASV	Precharge bias voltage input
2, 3, 4, 5, 6, 7, 9, 10, 11,12	1A1–1A10	Port 1A1 to Port 1A10
8, 17, 32, 41	GND	Ground (V)
13, 14, 16, 18, 19, 20, 21, 22, 23, 24	2A1–2A10	Port 2A1 to Port 2A10
15	V <sub>CC</sub>	Positive supply voltage
35, 34, 33, 31, 30, 29, 28, 27, 26, 25	2B1–2B10	Port 2B1 to Port 2B10
46, 45, 44, 43, 42, 40, 39, 38, 37, 36	1B1–1B10	Port 1B1 to Port 1B10
48, 47	1 <u>0E</u> , 2 <u>0E</u>	Switch enables

#### **FUNCTION TABLE**

ŌĒ	STATE
L	A Port = B Port
Н	A Port = Z
Н	B Port = BIASV

H = High voltage level

L = Low voltage level

Z = High impedance "off" state

#### **ABSOLUTE MAXIMUM RATINGS**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC clamp diode current	V <sub>I</sub> < 0	-50	mA
VI	DC input voltage <sup>1</sup>		-0.5 to +7.0	V
I <sub>SW</sub>	DC continuous channel current	$V_{O} = 0$ to $V_{CC}$	±128	mA
VBIASV	DC bias voltage		-0.5 to +7.0	V
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C
øJA	Plastic thin shrink small outline package (TSSOP)		104	°C/W

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	DADAMETED	LIM	UNIT		
STWBOL	PARAMETER	Min	Max		
V <sub>CC</sub>	DC supply voltage	4.0	5.5	V	
BIASV	DC supply voltage	1.3	V <sub>CC</sub>	V	
V <sub>IH</sub>	High-level input voltage (control pin)	2.0		V	
VIL	Low-level Input voltage (control pin)		0.8	V	
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C	

#### LOGIC SYMBOL



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#### **DC ELECTRICAL CHARACTERISTICS**

				LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	T <sub>amb</sub> = −40°C to +85°C			UNIT	
			Min	Typ <sup>1</sup>	Max	1	
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = 4.5V; I <sub>I</sub> = -18mA			-1.2	V	
l	Input leakage current (control pin)	V <sub>CC</sub> = 5.5V; V <sub>I</sub> = GND or 5.5V			±5	μΑ	
Ι <sub>Ο</sub>	Output bias current (B pins)	$V_{CC}$ = 4.5V; BiasV = 2.4V; $V_O$ = 0, $\overline{OE}$ = $V_{CC}$			-0.25	mA	
I <sub>CC</sub>	Quiescent supply current	$V_{CC}$ = 5.5V; $I_{O}$ = 0, $V_{I}$ = $V_{CC}$ or GND			2.5	mA	
$\Delta I_{CC}$	Control pins <sup>2</sup>	$V_{CC}$ = 5.5V, one input at 3.4V, other inputs at $V_{CC}$ or GND			2.5	mA	
Cl	Input capacitance per OE pin	$V_{I}=3V \text{ or } 0$		4.5		pF	
C <sub>O(OFF)</sub>	Capacitance per port (OFF-state)	$V_0 = 3V$ or 0; switch off		9.5		pF	
		$V_{CC} = 4.5V; V_{I} = 0V; I_{I} = 64mA$		5	7		
r <sub>on</sub> <sup>3</sup>	On-resistance	$V_{CC} = 4.5V; V_{I} = 0V; I_{I} = 30mA$		5	7	Ω	
		$V_{CC} = 4.5V; V_I = 2.4V; I_I = -15mA$		10	15	1	
V <sub>P</sub>	Pass voltage	$V_{IN} = V_{CC} = 4.5V; I_{out} = -100\mu A$	3.4	3.6	3.9	V	
I <sub>USP</sub>	Undershoot static current protection <sup>4</sup>			-10		mA	

NOTES:

All typical values are at VCC = 5V, TA = 25 C
This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND
Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

4. Force I<sub>USP</sub>, measure  $V_B \ge 3V$ 

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#### AC CHARACTERISTICS FOR $V_{CC}$ = 5.0V ±0.5V RANGE

GND = 0V;  $t_r = t_f \le 2.5$ ns;  $C_L = 50$ pF.

SYMBOL	PARAMETER	WAVEFORM	T <sub>am</sub>	<sub>o</sub> = -40 to +8	85°C	UNIT
			MIN	TYP <sup>1</sup>	MAX	
t <sub>pd</sub>	Propagation delay; An to Bn; Bn to An <sup>2</sup>	1			0.25	ns
t <sub>PZH</sub>	3-State output enable time OE to An; OE to Bn; BIASV = GND	2	1.3	3.1	5.3	ns
t <sub>PZL</sub>	3-State output enable time OE to An; OE to Bn; BIASV = 3.0V	2	1.4	2.9	4.6	ns
t <sub>PHZ</sub>	$\frac{3}{OE}$ to An; $\overline{OE}$ to Bn; BIASV = GND	2	1.7	2.8	4.5	ns
t <sub>PLZ</sub>	$\frac{3}{OE}$ to An; $\overline{OE}$ to Bn; BIASV = 3.0V	2	2.8	4.4	6.6	ns

NOTE:

1. All typical values are measured at  $T_{amb} = 25^{\circ}C$  and  $V_{CC} = 5.0V$ 2. Warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON-state resistance of the switch and a load capacitance of 50pF, when driven by an ideal voltage source (zero output impedance)

#### AC WAVEFORMS

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$ 



Waveform 1. Waveforms Showing the Input (An) to Output (Bn) **Propagation Delays** 



Waveform 2. Waveforms Showing the 3-State Output Enable and **Disable** Times

#### **TEST CIRCUIT AND WAVEFORMS**



#### NOTES:

- All input pulses are supplied by generators having the following 1. characteristics: PRR  $\leq$  10 MHz, Z\_O = 50  $\Omega,\,t_r \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- The outputs are measured one at a time with one transition per 2. measurement.

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VERSION PROJECTION	
VERSION IEC JEDEC EIAJ PROJECTION	ISSUE DATE
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NOTES

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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